

# **ENS210**



Relative Humidity and Temperature Sensor with I<sup>2</sup>C Interface

#### **ENS210 Datasheet**

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## **Content Guide**

General Description	3
Key Benefits and Features	3
Applications	4
Block Diagram	4
Pin Assignments	5
Absolute Maximum Ratings	6
Electrical Characteristics	7
I <sup>2</sup> C Timing Characteristics	8
Temperature Sensor Characteristics	8
Relative Humidity Sensor Characteristics	9
System Timing Characteristics	10
Functional Description	. 11
Temperature Sensor	12
Relative Humidity Sensor	13
RH Accuracy at Various Temperatures	14
The I <sup>2</sup> C Interface	15
I <sup>2</sup> C Operations on Registers	15
The I <sup>2</sup> C Slave Address	17
Sensor Control	17
Sensor Timing	18
The Sensor Readout Registers	
Computing CRC-7	21
Processing T_VAL and H_VAL	22
Reading PART_ID and UID	24
Register Description	. 25
Register Overview	25
Detailed Register Description	26
Register PART_ID (Address 0x00)	26
Register DIE_REV (Address 0x02)	26
Register UID (Address 0x04)	.26

Register SYS_CTRL (Address 0x10)	2/
Register SYS_STAT (Address 0x11)	27
Register SENS_RUN (Address 0x21)	28
Register SENS_START (Address 0x22)	28
Register SENS_STOP (Address 0x23)	29
Register SENS_STAT (Address 0x24)	29
Register T_VAL (Address 0x30)	
Register H_VAL (Address 0x33)	30
Application Information	31
Typical Application	31
Recommended Operating Conditions	32
Soldering & Storage Information	
Soldering	
Storage and Handling	
Reconditioning	
After Soldering	
After Extreme Conditions	36
Package Drawings & Markings	37
Marking Information	
Ordering & Central Information	20
Ordering & Contact Information RoHS Compliant & ScioSense	37
Koris compilant a sciosense	
Green Statement	40
Copyrights & Disclaimer	<b>4</b> 1
	71
Document Status	42
Revision Information	42
REVISION INIONINALION	43





## **General Description**

The ENS210 integrates one relative humidity sensor and one high-accuracy temperature sensor. The device is encapsulated in a QFN4 package and includes an I<sup>2</sup>C slave interface for communication with a master processor.

Ordering Information appears at the end of the datasheet.

# **Key Benefits and Features**

The benefits and features of ENS210, Relative Humidity and Temperature Sensor with I<sup>2</sup>C Interface are listed below:

Figure 1: Added Value of Using ENS210

Benefits	Features
Ultra-accurate	<ul> <li>Temperature sensor (±0.15°C)</li> <li>Relative humidity sensor (Typ:±2.0%RH)</li> </ul>
Wide sensing range	<ul> <li>Temperature operating range (-40°C to 100°C)</li> <li>Relative humidity operating range (0% to 100%)</li> </ul>
Wide operating voltage	• 1.71V to 3.60V
• Small foot-print	• 2.0mm x 2.0mm x 0.75mm
• Industry standard two-wire interface	• Standard (100kbit/s) and fast (400kbit/s) I <sup>2</sup> C
Low power	<ul> <li>Automatic low-power standby when not measuring</li> <li>Active current: 6.6µA @ 1Hz (1.8V)</li> <li>Standby current: 40nA</li> </ul>
Cost effective	<ul> <li>Digital pre-calibrated relative humidity and temperature sensor</li> <li>Output directly in %RH and Kelvin</li> <li>Wide supply voltage range</li> </ul>
High reliability	Long-term stability





## **Applications**

The ENS210 applications include:

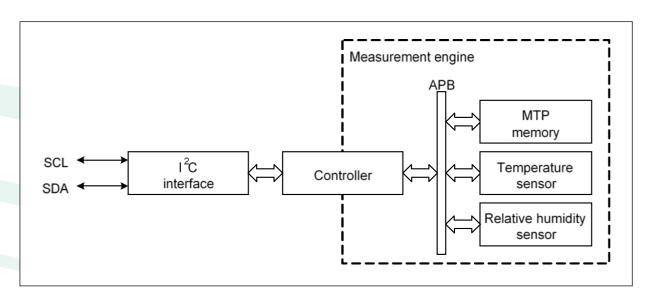
- Building Automation / Smart home / HVAC<sup>1</sup>
  - Indoor air quality detection
  - Demand-controlled ventilation
  - Smart thermostats
- Home appliances
  - Air cleaners / purifiers
  - Refrigerators, washing machines, dishwashers, dryers
- Mobiles / Wearables
- IoT devices
- Portable devices for personal health and wellness
- Weather stations

#### **Block Diagram**

The internal block diagram of ENS210 is shown in Figure 2. The I<sup>2</sup>C (communication) interface is connected to a controller which acts as the command interpreter and as bus master of the internal Advanced Peripheral Bus (APB). The memory and sensors are slaves of the APB. The MTP memory is used to store the sensor calibration parameters and unique ID.

To reduce power consumption the controller only powers the measurement engine when needed.

Figure 2: Functional Blocks of ENS210



#### Note(s):

1. HVAC = Heat, Ventilation and Air Conditioning





# **Pin Assignments**

The ENS210 pin assignment is described in Figure 3 and Figure 4.

Figure 3: Pin Diagram of ENS210

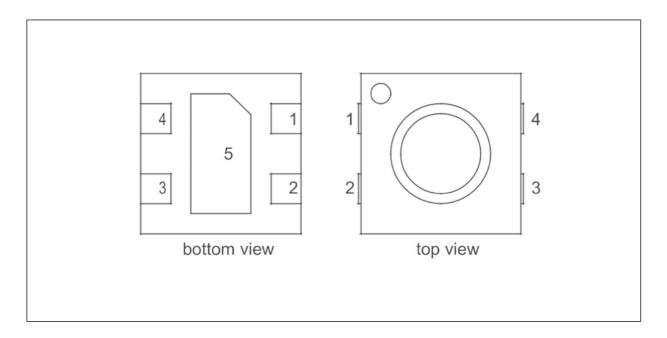


Figure 4: Pin Description of ENS210

Pin Number	Pin Name	Description
1	V <sub>DD</sub>	Supply voltage
2	SCL	I <sup>2</sup> C bus serial clock input (SCL)
3	SDA	I <sup>2</sup> C bus serial bidirectional data line (SDA)
4	V <sub>SS</sub>	Ground supply voltage; must be connected
5	V <sub>SS</sub>	Ground supply voltage; must be connected





## **Absolute Maximum Ratings**

Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated under Electrical Characteristics is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Figure 5:
Absolute Maximum Ratings of ENS210

Symbol	Parameter	Min	Max	Units	Comments		
		Electr	ical Paran	neters			
$V_{DD}$	Supply voltage	-0.30	4.60	٧			
I <sub>lu</sub>	Latch-up current	100		mA	$I/O$ ; -0.5 $V$ dd < $V_I$ < 1.5 $V$ dd; $T_j$ < 125 $^{\circ}$ C		
		Electro	Electrostatic Discharge				
ESD <sub>HBM</sub>	Human body model; all pins	±20	000	٧	JEDEC JS-001-2014		
ESD <sub>CDM</sub>	Charged model device; all pins	±500		٧	JEDEC JS-002-2014		
	(	Operating a	nd Storage	e Condition	ns		
MSL	Moisture sensitivity level	1			Maximum floor life time is unlimited		
T <sub>STRG</sub>	Storage temperature	10	50	°C			
RH <sub>NC</sub>	Relative humidity (non-condensing)	20	60	%RH	Preferably in sealed ESD bag		
$T_A$	Operating ambient temperature	-40	100	°C			
$H_A$	Operating ambient relative humidity	0	100	%RH			





#### **Electrical Characteristics**

All limits are guaranteed. The parameters with min and max values are guaranteed with production tests or SQC (Statistical Quality Control) methods.

Figure 6: Electrical Characteristics

Symbol	Parameter	Conditions	Min	Тур (1)	Max	Unit
V <sub>DD</sub>	Supply voltage	Max ripple $100 \text{mV}_{PP}$ between $0\text{-}1 \text{MHz}$	1.71	1.80 (3.30)	3.60	٧
		Standby state		0.04 (0.5)		μΑ
I <sub>DD</sub>	Supply current	Continuous run mode		58 (61)		μΑ
		T and RH measurement at 1Hz		6.6 (7.1)		μΑ
V <sub>IH</sub>	High-level input voltage		0.7×V <sub>DD</sub>		V <sub>DD</sub> +0.5	٧
V <sub>IL</sub>	Low-level input voltage		-0.5		0.3×V <sub>DD</sub>	٧
	Low-level	$V_{OL} = 0.4V$	3			mA
I <sub>OL</sub>	output current	V <sub>OL</sub> = 0.6V	6			mA

<sup>1.</sup> Values in parenthesis are for  $V_{DD}$ =3.30 V.

 $<sup>2.</sup>T_{\textrm{A}}$  = 25  $^{\circ}\textrm{C}$  and at 1.80 V supply voltage, unless otherwise specified





## I<sup>2</sup>C Timing Characteristics

ENS210 is compliant to the I<sup>2</sup>C standard; it supports standard and fast mode as per I<sup>2</sup>C-bus specifications [UM10204, I<sup>2</sup>C-bus specification and user manual, Rev. 6, 4 April 2014].

# **Temperature Sensor Characteristics**

Figure 7: Temperature Sensor Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$T_{range}$	Temperature range		-40		100	°C
_	Temperature	$T_A = 0$ °C to $70$ °C;		0.15	0.2	°C
T <sub>acc</sub>	accuracy <sup>3</sup>	$T_A = -40^{\circ} C \text{ to } 100^{\circ} C;$			0.3	°C
$T_{res}$	Temperature resolution			0.016		°C
t <sub>resp</sub>	Response time <sup>2</sup>	T step of $10^{\circ}$ C by submersion (in $0^{\circ}$ C to $70^{\circ}$ C range); $\tau 63 \%$ <sup>1</sup>		1		S
$T_{rep}$	Temperature repeatability	3σ of consecutive measurement values at constant conditions	-0.1		0.1	°C
ΔΤ	Temperature long term drift			0.005		°C/year

#### Note(s):

<sup>1.63%</sup> indicates that if a T step of  $10^{\circ}$ C, e.g. from  $20^{\circ}$ C to  $30^{\circ}$ C is made, it will take  $t_{resp}$  seconds to reach 63% of that step. 2.In an application the temperature response time depends on heat conductivity of the sensor PCB.

<sup>3.</sup> Typical and maximum accuracy specification refers to, respectively, 2 and 3 standard deviations, assuming normal distribution of accuracy errors. After industrial calibration, on each production lot through statistical analysis, a population of sensors is tested on typical room conditions (e.g. 25°C, 45%RH) and only lots passing the verification qualify for customer deliveries.





# **Relative Humidity Sensor Characteristics**

Figure 8: Relative Humidity Sensor Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$H_{range}$	Relative humidity range		0		100	%RH
	Relative humidity	T <sub>A</sub> =25°C; RH=0%RH to 85% RH; excluding hysteresis		2	3	%RH
H <sub>acc</sub>	accuracy <sup>3</sup>	T <sub>A</sub> =25°C; RH=>85%RH to 95% RH; excluding hysteresis		3	4	%RH
$H_{res}$	Relative humidity resolution			0.03		%RH
t <sub>resp</sub>	Response time <sup>4</sup>	RH step of 20%RH (in 40%RH to 80%RH range); $\tau$ 63% <sup>1</sup> ; 1m/s flow; $T_A = 25$ °C			3	s
H <sub>hys</sub>	Relative humidity hysteresis	$T_A = 25$ °C; RH = 20%RH to 90%RH; 2 hours exposure time		±0.55		%RH
H <sub>rep</sub>	Relative humidity repeatability	$3\sigma$ of consecutive measurement values at $T_A = 25^{\circ}C$ and RH = $40\%RH$		±0.1		%RH
ΔΗ	Relative humidity long term drift <sup>2</sup>	T <sub>A</sub> = 25°C		0.25		%RH/year

#### Note(s):

<sup>1.63%</sup> indicates that if an RH step of 20%RH is made, e.g. from 40%RH to 60%RH, it will take  $t_{resp}$  seconds to reach 63% of that step.

<sup>2.</sup> Values are linearized averages over the lifetime of the product. Due to non-linear behavior a larger drift is expected in the first years.

<sup>3.</sup> Typical and maximum accuracy specification refers to, respectively, 2 and 3 standard deviations, assuming normal distribution of accuracy error.

 $<sup>{\</sup>it 4.}\, {\it Device only performance.}\, {\it Application response time will depend on the design-in of the sensor}$ 





# **System Timing Characteristics**

Figure 9: System Timing Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t <sub>booting</sub>	Booting time <sup>1</sup>			1	1.2	ms
		T only, single shot (includes t <sub>booting</sub> )		105	110	ms
	t <sub>conv</sub> Conversion time	T only, continuous		104	109	ms
Conv		T and RH, single shot (includes t <sub>booting</sub> )		122	130	ms
		T and RH, continuous		225	238	ms

<sup>1.</sup> Time in transient state booting (see Figure 10).



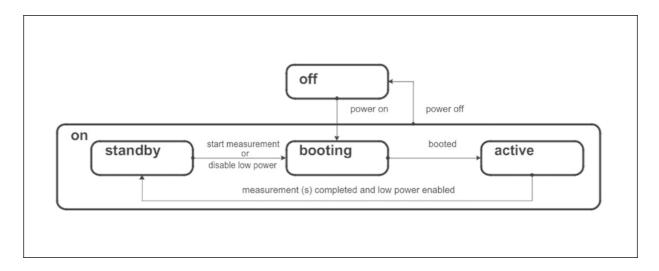


#### **Functional Description**

The ENS210 integrates two sensor blocks: temperature and relative humidity.

The device is normally in the *standby* state (Figure 10): the measurement engine (see Figure 2) is unpowered, but the I<sup>2</sup>C interface is operational and register write/read operation can be performed. When a measurement command is given, the device is first *booting* to *active* then it starts a measurement. When the measurement is completed, the device returns to the *standby* state. Since the I<sup>2</sup>C interface is operational in *standby*, the measurement result can be read out.

Figure 10: The ENS210 Power States



In continuous run mode (see Register SENS\_RUN) or when low power is disabled (see Register SYS\_CTRL), the device remains in *active* state.

The system power status is observable (see Register SENS\_STAT).

When powering up from *off*, the device is first booting to active, but then falls immediately back to *standby* (since no measurement is pending, and by default low power is enabled).

Note that the booting state is a transient state (the system automatically transitions to the next state - *active*); the booting time is given in Figure 9.

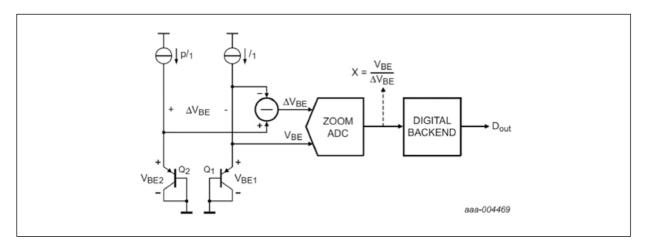




#### **Temperature Sensor**

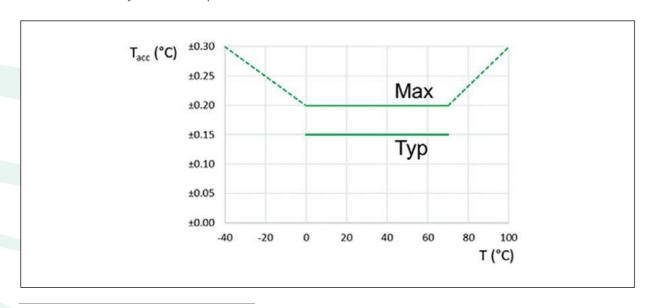
The temperature sensor block (Figure 11) determines the ambient temperature, and outputs a calibrated value in Kelvin.

Figure 11:
Band Gap Temperature Measurement



The temperature is measured using a high-precision (12 bits) zoom-ADC. The analog part is able to measure a strongly temperature dependent  $X = V_{BE}/\Delta V_{BE}$ . The X is found by first applying a coarse search (successive approximation), and then a sigma-delta in a limited range. The accuracy of the sensor is shown in Figure 12. The conversion time is shown in Figure 9.

Figure 12:
Absolute Accuracy of the Temperature Sensor



#### Note(s):

1. Dash line indicates natural physical behavior

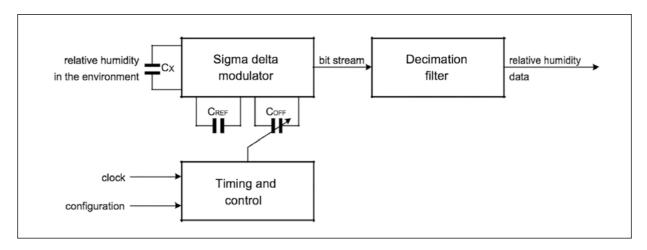




#### **Relative Humidity Sensor**

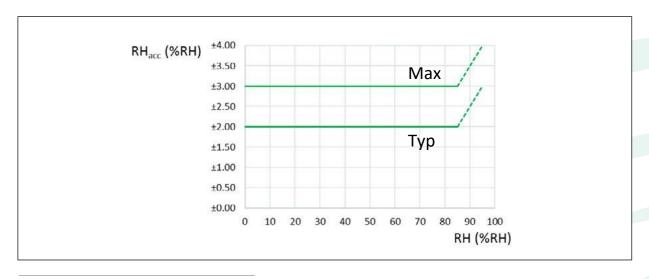
The relative humidity sensor as shown in Figure 13 determines the ambient relative humidity and outputs a calibrated value in %RH. The transducer (the  $C_X$  on the top left) consists of a large-area capacitor covered with a humidity-sensitive material. The capacitance change is proportional to the change in relative humidity, and has a linear dependence on temperature. The capacitance is measured by a high-precision  $2^{nd}$  order sigma-delta converter.

Figure 13: Relative Humidity Sensor



Reading the relative humidity sensor will output a temperature compensated value. The accuracy of the sensor is shown in Figure 14. The conversion time is shown in Figure 9.

Figure 14: Absolute Accuracy of the Relative Humidity Sensor at 25°C



#### Note(s):

1. Dash line indicates natural physical behavior

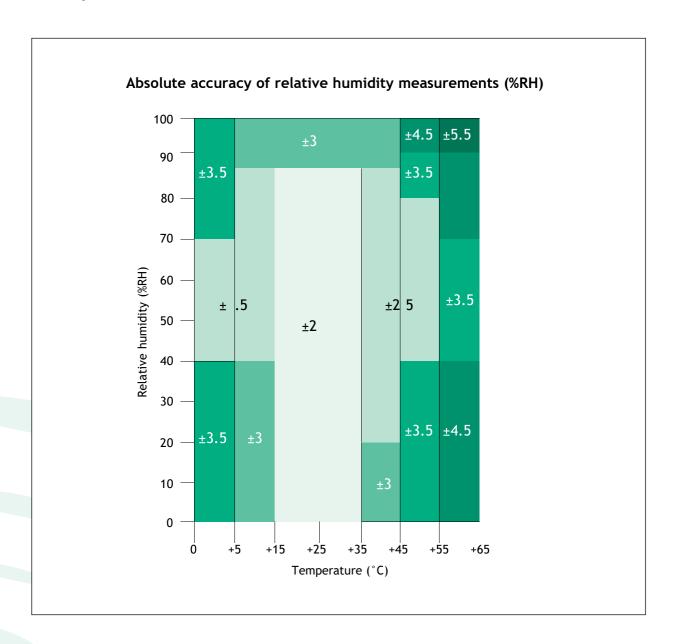




## RH Accuracy at Various Temperatures

Typical RH accuracy at 25°C is defined in Figures 8 and 14. The relative humidity accuracy has also been evaluated at temperatures other than 25°C. The values shown in Figure 15 are an indication only, which may be important for your application, but are not guaranteed.

Figure 15: Accuracy of Relative Humidity Measurements (%RH) as Function of Temperature and Relative Humidity







#### The I<sup>2</sup>C Interface

The ENS210 is an  $I^2C$  slave device. The  $I^2C$  interface supports standard (100kbit/s) and fast (400kbit/s) mode.

Details on  $I^2C$  protocol is according to  $I^2C$ -bus specifications [UM10204,  $I^2C$ -bus specification and user manual, Rev. 6, 4 April 2014].

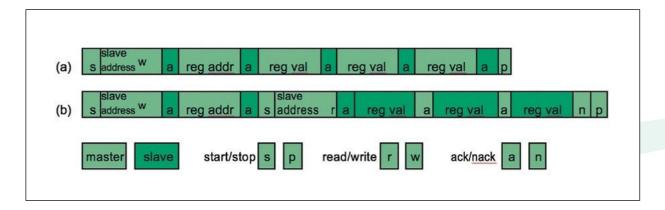
The device applies all mandatory I<sup>2</sup>C protocol features for slaves: START, STOP, Acknowledge, 7-bit slave address. ENS210 does not use clock stretching.

None of the other optional features (10-bit slave address, General Call, Software reset, or Device ID) are supported, nor are the master features (Synchronization, Arbitration, START byte).

#### I<sup>2</sup>C Operations on Registers

The ENS210 uses a register model to interact with it. This means that an I<sup>2</sup>C master can write a value to one of the registers of a slave, or that it can read from one of the registers of the slave. In the ENS210, registers are addressed using 1 byte. The values stored in a register are also 1 byte. However, the ENS210 implements "auto increment" which means that it is possible to read, for example, two bytes by supplying the address of the first byte and then reading two bytes.

Figure 16: I<sup>2</sup>C Transaction Formats



A typical *write* transaction (see Figure 16) therefore has the following format. The master initiates a transaction with a so-called start condition "s". This blocks the bus. Next, the master sends the 7 bits ENS210 *slave address* followed by a 1 bit direction (a 0 indicating write "w"). This byte is acknowledged "a" by the slave. The master continues by sending the 8 bit *register address*, which is acknowledged by the slave.





This register address is stored in an internal CRA register ("Current Register Address"). Finally, the master sends the 8 bit *register value*, which is acknowledged by the slave (or nack'ed when the address is not writeable). This value is written to the register pointed to by the CRA, and the CRA is incremented by

1.Optionally, the master sends more 8 bit values, for the next registers (auto incrementing CRA), each of which is (n)ack'ed by the slave. Finally, the master generates a stop condition "p", unblocking the bus for other transactions.

A *read* transaction (see Figure 16) starts with a write (of the register address), followed by a read. Consequently, it has the following format. The master initiates the transaction with a start condition. Next, the master sends the 7 bits ENS210 *slave address* followed by a 1 bit direction (a 0 indicating write). This byte is acknowledged by the slave. The master continues by sending the 8 bit *register address*, which is acknowledged by the slave and stored in the CRA register. Then the master sends another start condition (a so-called repeated start condition, keeping the bus blocked) followed by the 7 bits ENS210 *slave address* followed by a 1 bit direction (a 1 indicating read "r"), which is acknowledged by the slave. Next, the slave sends an 8 bits *register value* from the register pointed to by the CRA register, and the CRA is incremented by 1. This byte is acknowledged by the master. The master may read another 8 bits (auto increment feature) from the slave and acknowledge that, until the master sends a nack "n" followed by a stop to unblock the bus.

The ENS210 has an 8 bit address space, potentially addressing 256 registers. In reality, only few addresses are actually backed by a register (see Register Overview). All other addresses are reserved. A write transaction to a reserved (or read-only) register causes a not-acknowledge. A read transaction for a reserved register will return a 0.





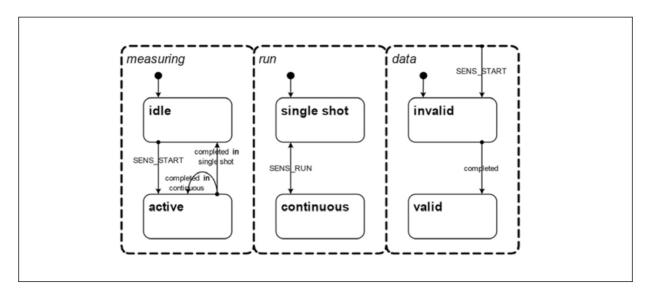
#### The I<sup>2</sup>C Slave Address

The ENS210 is an  $I^2C$  slave device with a fixed slave address of 0x43. This means that the first byte after a start condition is 1000 011x, where x indicates the data direction, so 0x86 (1000 0110) for write and 0x87 (1000 0111) for read.

#### **Sensor Control**

The ENS210 contains a temperature and a relative humidity sensor. Both sensors have two run modes: single shot run mode and continuous run mode (enabled via SENS\_RUN), see Figure 17.

Figure 17: The Sensor Modes



When in the *single shot* run mode, starting a measurement is under control of the master. By default a sensor is idle; it can be started by writing a 1 to the corresponding bit in SENS\_START. After a start, the sensor stops when the measurement is completed. Whether a sensor is idle or active measuring can be detected by reading SENS\_STAT. The measured values can be obtained via their respective readout registers (T\_VAL and H\_ VAL). Writing to SENS\_STOP in single shot has no effect.

When in the *continuous* run mode, the sensor performs measurement after measurement after a 1 is written to the corresponding bit in SENS\_START. The result of each measurement is stored in the aforementioned readout registers. Writing 1 to the corresponding bit in SENS\_STOP stops the repeat cycle after the ongoing measurement is completed.





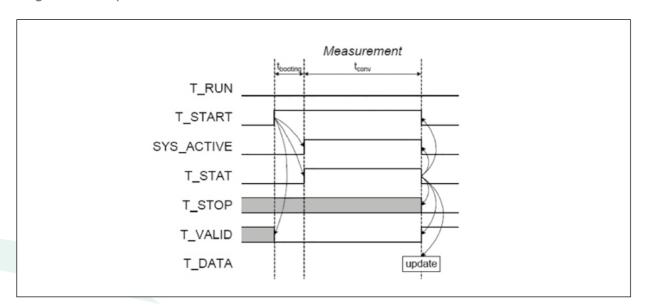
The device operates in a step-wise way. In each step, either one or both sensors are active. The step ends when the measurement(s) are completed. For the next step, the device inspects its register settings, and either one or both sensors are activated again, or there is no measurement request and the device goes into standby (unless low power is disabled by SYS\_ CTRL).

This means that multiple writes to START during a step have no effect; the measurement is started once, and only a write to START after the measurement has completed starts the measurement again. Similarly, multiple writes to STOP have no effect; when the measurement completes (in continuous mode) the stop request is effectuated once. When START and STOP are both requested, the measurement is started, and when completed, stopped.

#### **Sensor Timing**

There are differences between single shot measurements and continuous measurements. Figure 18 shows the timing of a single shot T measurement.

Figure 18: Single Shot Temperature Measurement



Signal T\_RUN is written low to select a single shot measurement. Note that T\_STOP is typically low (cleared by a previous measurement), but its state is ignored in a single shot measurement. T\_START is written high to start measuring: T\_VALID in T\_VAL is cleared and the device starts booting to active. Once active SYS\_ACTIVE goes high, and measurement starts (T\_STAT goes high).

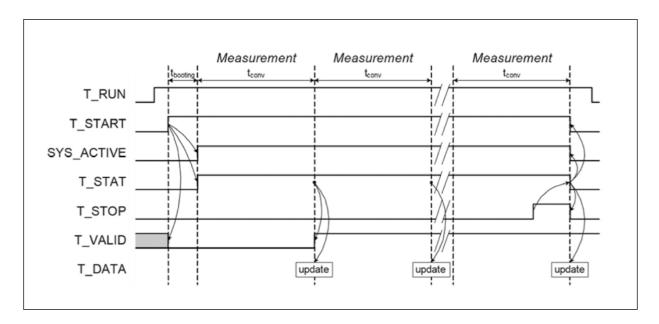
When the measurement is completed (T\_STAT goes low) the data register (T\_DATA) becomes valid (T\_VALID goes high) and the device goes back to *standby* (SYS\_ACTIVE goes low). The T\_START and T\_STOP are cleared.





Figure 19 shows the timing of a continuous T measurement.

Figure 19: Continuous Temperature Measurement



Signal T\_RUN is written high to select a continuous measurement. Note that T\_STOP is typically low (cleared by a previous measurement), and it should stay low otherwise continuous mode will stop after one measurement. T\_START is written high to start measuring: T\_VALID in T\_VAL is cleared and the device starts *booting* to *active*. Once *active* SYS\_ACTIVE goes high, and measurement starts (T\_STAT goes high).

When the first measurement is completed the data register (T\_DATA) becomes valid (T\_VALID goes high), and the device starts a new measurement. When the next measurement is completed the data register (T\_DATA) is updated; T\_VALID stays high. The device starts a new measurement.

At some point in time, a stop command is given (T\_STOP is written high). As soon as the current measurement is completed, the data register (T\_DATA) is once more updated and the device goes back to *standby* (SYS\_ACTIVE goes low). The T\_START and T\_STOP are cleared.

Note that writes to the SENS\_XXX registers only take effect when no measurement is ongoing. In other words, measurements are always sequential (so we can have three types: T only, RH only or T and RH and changes occur when the measurements are finished.

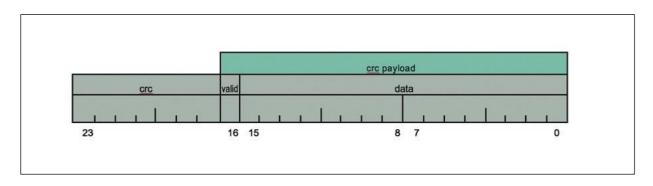




#### The Sensor Readout Registers

The sensor readout registers (T\_VAL and H\_VAL) consist of three parts: the actual measured data, a valid flag and a checksum (see Figure 20). It is not mandatory to read the valid flag or the checksum when reading the data.

Figure 20: The Layout of the Sensor Readout Registers



The *checksum* is a cyclic redundancy check over the data and the valid flag; the stored checksum is the result of CRC-7 (polynomial x7+x3+1, see *https://en.wikipedia.org/wiki/Cyclic\_redundancy\_check*) with 0x7F as initial vector (*i.e. with all bits flipped*), see Computing CRC-7 for sample C code.

The *valid* flag is cleared when a measurement is started (irrespective of the run mode). Once the measurement is completed the valid flag is set. In continuous mode, a new measurement is then started without clearing the valid flag; so data is always valid after the first measurement (but it might be several milliseconds old).

The *data* field is a 16 bits fixed point number, whose format and unit depends on the sensor (see Register T\_VAL and Register H\_VAL).

To ensure consistent view, these multi-byte readout registers are double buffered. When the first byte (i.e. the byte with the lowest register address) is read, the device copies all bytes from the measurement registers to the I<sup>2</sup>C registers, and then the value from the first I<sup>2</sup>C register is returned. Reads to the other bytes of the multi-byte register (i.e. with higher register addresses) are always directly from the I<sup>2</sup>C registers.





#### Computing CRC-7

CRC algorithm uses a 7 bit polynomial (see lines 4, 5, and 6), and a 17 bit payload. The <code>crc7()</code> function below uses the following constants defining the CRC width, (the coefficients of the) polynomial and the initial vector (start value of the CRC), and some constants describing the payload data size.

```
7654
                                      3211
// Polynomial
                        0b
                              1000
                                      1001 \sim x^7+x^3+x^0
//
                        0x
#define CRC7WIDTH
                        7
                              // 7 bits CRC has polynomial of 7th order (has 8 terms)
#define CRC7POLY
                        0x89 // The 8 coefficients of the polynomial
#define CRC7IVEC
                        0x7F // Initial vector has all 7 bits high
// Payload data
                       17
#define DATA7WIDTH
                        ((1UL<<DATA7WIDTH)-1) // 0b 0 1111 1111 1111 1111
#define DATA7MASK
#define DATA7MSB
                        (1UL<<(DATA7WIDTH-1)) // 0b 1 0000 0000 0000 0000
```

The crc7 (val) function returns the CRC-7 of a 17 bits value val.

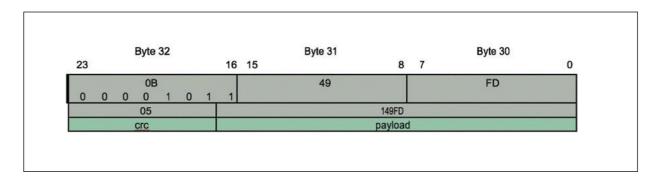
```
// Compute the CRC-7 of 'val' (should only have 17 bits) uint32_t crc7( uint32_t val ) {
     // Setup polynomial
     uint32_t pol= CRC7POLY;
     // Align polynomial with data
     pol = pol << (DATA7WIDTH-CRC7WIDTH-1);</pre>
     // Loop variable (indicates which bit to test, start with highest)
     uint32 t bit = DATA7MSB;
     // Make room for CRC value
    val = val << CRC7WIDTH;</pre>
     bit = bit << CRC7WIDTH;
     pol = pol << CRC7WIDTH;
     // Insert initial vector
    val |= CRC7IVEC;
     // Apply division until all bits done
     while( bit & (DATA7MASK<<CRC7WIDTH) ) {</pre>
        if( bit & val ) val ^= pol;
        bit >>= 1;
        pol >>= 1;
     return val;
}
```





Suppose that T\_VAL (address 30, 31 and 32) reads FD 49 0B, corresponding (little endian) with the number 0B49FD, see Figure 21. This leads to a CRC of 05 over a payload of 149FD. See the next paragraph for details on processing this data.

Figure 21: T\_VAL Readout



## Processing T\_VAL and H\_VAL

This paragraph shows a possible implementation of reading T and RH.

The following fragment starts a combined single shot measurement, waits and reads the measurement results. It assumes the availability of i2c\_reg\_write and i2c\_reg\_read primitives as well as a sleep routine (rtk\_tsk\_sleep). The format specifiers in the printf's are kept simple (%d instead of %ld or even PRId32 from inttypes.h); they need adaptation on e.g. 16 bits platforms.

```
// Record I<sup>2</sup>C transaction status
bool i2c_ok= true;
// Start T and H (write 03 to register 22 in device 86)
uint8_t wbuf[]= { 0x03 };
i2c_ok &= i2c_reg_write(0x86, 0x22, wbuf, sizeof wbuf );
// Wait for measurements to complete
#define CONVERSION_TIME_T_H_MS 130
rtk_tsk_sleep(CONVERSION_TIME_T_H_MS);
// Read T and H (read 6 bytes starting from 0x30 in device 86)
uint8_t rbuf[6];
i2c_ok &= i2c_reg_read(0x86, 0x30, rbuf, sizeof rbuf );
// Extract T_VAL and H_VAL (little endian), assumes 32 bits
wordsize uint32_t t_val= (rbuf[2]<<16) + (rbuf[1]<<8) + (rbuf[0]<<0);
uint32_t h_val= (rbuf[5]<<16) + (rbuf[4]<<8) + (rbuf[3]<<0);</pre>
```





The following fragment processes the T measurement as available in  $t_val$ . It relies on the crc7() function as shown previously.

```
// Extract (and print) the fields
uint32_t t_data = (t_val>>0 ) & 0xffff;
uint32_t t_valid= (t_val>>16) & 0x1;
uint32_t t_crc = (t_val>>17) & 0x7f;
printf("ENS210: T: %06x %02x %01x %04x\n", t_val, t_crc, t_valid,
t_data ); // Check the CRC
uint32_t t_payl = (t_val>>0 ) & 0x1ffff;
bool t_crc_ok= crc7(t_payl)==t_crc;
// Convert to float (and print)
float TinK = (float)t_data / 64; // Temperature in Kelvin
float TinC = TinK - 273.15; // Temperature in Fahrenheit
printf("ENS210: T: (i2c=%d crc=%d valid=%d) %5.1fK %4.1fC %4.1fF\n", i2c_ok, t_crc_ok, t_valid,
TinK, TinC, TinF );
```

The following fragment processes the RH measurement as available in  $h_val$ . It is similar to the  $t_val$  processing.

```
// Extract (and print) the fields
uint32_t h_data = (h_val>>0 ) & 0xffff;
uint32_t h_valid= (h_val>>16) & 0x1;
uint32_t h_crc = (h_val>>17) & 0x7f;
printf("ENS210: H: %06x %02x %01x %04x\n", h_val, h_crc, h_valid,
h_data ); // Check the CRC
uint32_t h_payl = (h_val>>0 ) & 0x1ffff;
bool h_crc_ok= crc7(h_payl)==h_crc;
// Convert to float (and print)
float H = (float)h_data/512; // relative humidity (in %)
printf("ENS210: H: (i2c=%d crc=%d valid=%d) %2.0f%%\n", i2c_ok, h_crc_ok, h_valid, H );
```

If registers 30 to 35 would contain fd 49 0b 6c 2e f5 (i.e.  $T_VAL$  in blue and  $H_VAL$  in green)the code would print

```
ENS210: T: 0b49fd 05 1 49fd
ENS210: T: (i2c=1 crc=1 valid=1) 296.0K 22.8C 73.0F
ENS210: H: f52e6c 7a 1 2e6c
ENS210: H: (i2c=1 crc=1 valid=1) 23%
```





## Reading PART\_ID, DIE\_REV and UID

The first 3 registers (PART\_ID, DIE\_REV and UID) are only available in *active* state. There are two ways to read them:

- · Dedicated read action
  - Disable low power (set LOW\_POWER to 0)
  - Wait for  $t_{booting}$  to get into *active* state (check SYS\_ACTIVE to be 1)
  - Read the ID register(s)
  - Re-enable low power (set LOW\_POWER to 1)
- Piggybacking on a measurement
  - Start a measurement (write 0b01, 0b10, or 011 to SENS\_START)
  - Wait for t<sub>booting</sub> to get into active state (check SYS\_ACTIVE to be 1)
  - Read the ID register(s)
  - Ensure the device is still in *active* state (check SYS\_ACTIVE to be 1)





## **Register Description**

This section describes the I<sup>2</sup>C registers of the ENS210.

# **Register Overview**

Note that some registers are actually spread over multiple addresses. For example, T\_VAL at address 30 is spread over 3 addresses (its "Size" is 3). This could be rephrased as follows: there are three registers T\_VAL0, T\_VAL1, and T\_VAL2 at addresses 30, 31, and 32 respectively.

Figure 22: Register Overview

Address	Name	Size	Access	Description
0x00	PART_ID	2	Read (active only)	Identifies the part as ENS210
0x02	DIE_REV	2	Read (active only)	Identifies the die revision version
0x04	UID	8	Read (active only)	Unique identifier
0x0C	<reserved></reserved>	4		
0x10	SYS_CTRL	1	Read/Write	System configuration
0x11	SYS_STAT	1	Read	System status
0x12	<reserved></reserved>	14		
0x21	SENS_RUN	1	Read/Write	The run mode (single shot or continuous)
0x22	SENS_START	1	Write	Start measurement
0x23	SENS_STOP	1	Write	Stop continuous measurement
0x24	SENS_STAT	1	Read	Sensor status (idle or measuring
0x25	<reserved></reserved>	11		
0x30	T_VAL	3	Read	Temperature readout
0x33	H_VAL	3	Read	Relative humidity readout
0x36	<reserved></reserved>	202		





## **Detailed Register Description**

Register PART\_ID (Address 0x00)

This 2 byte register identifies the part number in little endian (ENS210). This register is only available in *active* state; see Reading PART\_ID, DIE\_REV and UID for instructions of reading it.

Figure 23: Register PART\_ID

Addr	ess 0x00	PART_ID				
Bits	Field Name	Default	Access	Field Description		
15:0	PART_ID	0x0210	Read	Identifies this device as an ENS210		

#### Register DIE\_REV (Address 0x02)

This 2 byte register identifies the die revision number of the ENS210 device. This register is only available in active state; see Reading PART\_ID, DIE\_REV and UID for instructions of reading it.

Figure 24: Register DIE\_REV

Addr	ess 0x02	DIE_REV				
Bits	Field Name	Default	Access	Field Description		
15:0	DIE_REV	0x0001	Read Identifies the die revision version number			

#### Register UID (Address 0x04)

This 8 byte register uniquely identifies a single device among all ENS210 devices. This register is only available in active state; see Reading PART\_ID, DIE\_REV and UID for instructions of reading it.

Figure 25: Register UID

Addr	ess 0x04			UID
Bits	Field Name	Default	efault Access Field Description	
63:0	UID	Varies	Read Unique device id	





## Register SYS\_CTRL (Address 0x10)

This 1 byte register controls the system.

Figure 26:

Register SYS\_CTRL

Addr	ess 0x10			SYS_CTRL
Bits	Field Name	Default	Access	Field Description
7	RESET	0	Write	Write 1 to reset the device
6:1	<reserved></reserved>	0b000000	Read/Write	Keep to 0's
0	LOW_ POWER	0b1	Read/Write	Controls the automatic low power.  0: Disabled (device stays in <i>active</i> )  1: Enabled (device goes to <i>standby</i> when measurement complete)

## Register SYS\_STAT (Address 0x11)

This 1 byte register indicates the system status.

Figure 27:

Register SYS\_STAT

Addr	Address 0x11			SYS_STAT
Bits	Field Name	Default	Access	Field Description
7:1	<reserved></reserved>	0ь0000000	Read	Reads 0's
0	SYS_ACTIVE	0b1	Read	The system power state  0: System is in <i>standby</i> or booting state  1: System is in <i>active</i> state





## Register SENS\_RUN (Address 0x21)

This 1 byte register configures the run modes (single shot or continuous) of the sensors.

Figure 28: Register SENS\_RUN

Adc	Address 0x21			SENS_RUN
Bits	Field Name	Default	Access	Field Description
7:2	<reserved></reserved>	0ь000000	Read/Write	Keep to 0's
1	H_RUN	0b0	Read/Write	The run mode of the relative humidity sensor  0: Relative humidity sensor operates in single shot mode  1: Relative humidity sensor operates in continuous mode
0	T_RUN	0b0	Read/Write	The run mode of the temperature sensor  0: Temperature sensor operates in single shot mode  1: Temperature sensor operates in continuous mode

## Register SENS\_START (Address 0x22)

This 1 byte register starts a measurement for the sensors.

Figure 29: Register SENS\_START

Add	ress 0x22			SENS_START
Bits	Field Name	Default Access		Field Description
7:2	<reserved></reserved>	0b000000	Read/Write	Keep to 0's
1	H_START	0ь0	Read/Write	Write a 1 to start a relative humidity sensor measurement Writing 0 has no effect (helps in multiple access)
0	T_START	0b0	Read/Write	Write a 1 to start a temperature sensor measurement Writing 0 has no effect (helps in multiple access)





## Register SENS\_STOP (Address 0x23)

This 1 byte register stops a continuous measurement for the sensors.

Figure 30: Register SENS\_STOP

Add	ress 0x23		SENS_STOP	
Bits	Field Name	Default	Access	Field Description
7:2	<reserved></reserved>	0ь000000	Write	Write 0's
1	H_STOP	0b0	Write	Write a 1 to stop a continuous relative humidity sensor measurement Writing 0 has no effect (helps in multiple access)
0	T_STOP	0b0	Write	Write a 1 to stop a continuous temperature sensor measurement Writing 0 has no effect (helps in multiple access)

#### Register SENS\_STAT (Address 0x24)

This 1 byte register indicates the measuring status (idle or active) of the sensors.

Figure 31: Register SENS\_STAT

Add	ress 0x24			SYS_STAT
Bits	Field Name	Default	Access	Field Description
7:2	<reserved></reserved>	0ь000000	Read	Write 0's
1	H_STAT	0b0	Read	Indicates the measuring status of the relative humidity sensor  0: Relative humidity sensor is idle (not measuring)  1: Relative humidity sensor is active measuring
0	T_STAT	0b0	Read	Indicates the measuring status of the temperature sensor  0: Temperature sensor is idle (not measuring)  1: Temperature sensor is active measuring





#### Register T\_VAL (Address 0x30)

This 3 byte register contains the last measured temperature data. Furthermore it has a data valid flag and a CRC over the former two. Note that these bytes are double buffered; they are latched in by accessing the first byte, see The Sensor Readout Registers for details.

See Section Processing T\_VAL and H\_VAL for example code of processing this register.

Figure 32: Register T\_VAL

Add	ress 0x30	T_VAL		
Bits	Field Name	Default	Access	Field Description
23:17	T_CRC	-	Read	CRC over T_DATA and T_VALID
16	T_VALID	-	Read	Data valid indication (1 means T_DATA is valid)
15:0	T_DATA	-	Read	Last measured temperature, stored as a little endian 16 bits unsigned value in 1/64 Kelvin

#### Register H\_VAL (Address 0x33)

This 3 byte register contains the last measured relative humidity data. Furthermore it has a data valid flag and a CRC over the former two. Note that these bytes are double buffered; they are latched in by accessing the first byte, see The Sensor Readout Registers for details.

See Processing T\_VAL and H\_VAL for example code of processing this register.

Figure 33: Register H\_VAL

Add	lress 0x33	H_VAL		
Bits	Field Name	Default	Access	Field Description
23:17	H_CRC	-	Read	CRC over H_DATA and H_VALID
16	H_VALID	-	Read	Data valid indication (1 means H_DATA is valid)
15:0	H_DATA	-	Read	Last measured relative humidity, stored as a little endian 16 bits unsigned value in 1/512%RH



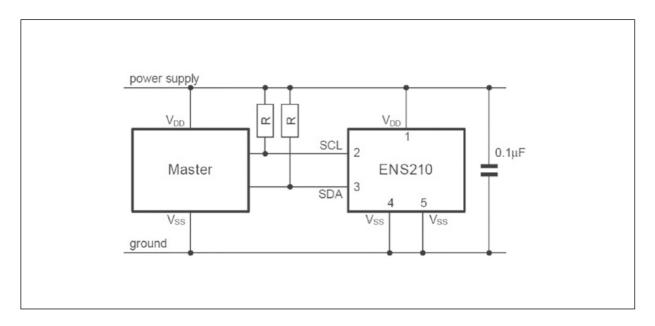


# **Application Information**

# Typical Application

Figure 34 shows a typical application.

Figure 34: ENS210 Typical Application







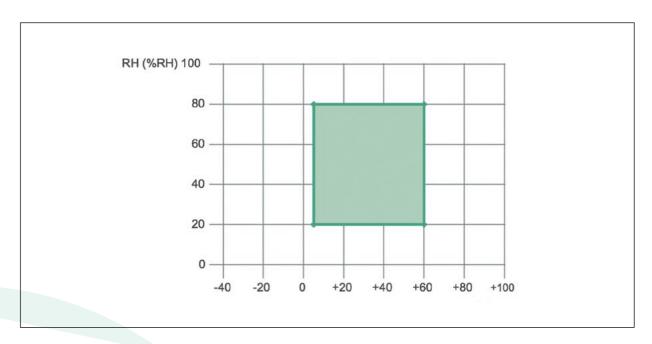
#### **Recommended Operating Conditions**

The recommended temperature and relative humidity operating range for the ENS210 is 5°C to 60°C and 20%RH to 80%RH, see Figure 35. Long term exposure outside these recommended operating conditions may temporarily offset the relative humidity readout.

After such exposure, the device will slowly return to its accuracy limits at 25°C (can be matter of hours or weeks, depending on stress conditions). Re-conditioning (bake + hydration) will accelerate kinetics of returning to its accuracy limits at 25°C.

Prolonged exposure to extreme conditions may accelerate drift, which might not be fully recoverable: e.g. after 96h at 85°C/85%RH offset can be around +6%RH.

Figure 35: Recommended Operating Conditions





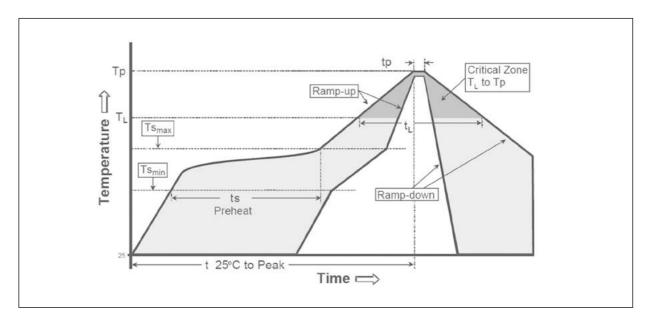


# Soldering & Storage Information

## Soldering

The ENS210 uses a cavity package. This package can be soldered using a standard reflow process in accordance with IPC/JEDEC J-STD-020D. See picture below.

Figure 36: Soldering Recommendations



The detailed settings for the reflow profile can be derived from this table.

Figure 37: Soldering Recommendations Table

Reflow Profile Settings				
T <sub>P</sub>	260°C			
tP (time within 5°C of TP)	20-40 seconds			
T <sub>L</sub>	217°C			
$t_L$	60-150 seconds			
Ts <sub>max</sub>	200°C			
Ts <sub>min</sub>	150°C			
t <sub>s</sub> (preheat)	60 to 180 seconds			
t 25°C to Peak	8 minutes max.			
ramp up	3°C/second max.			
ramp down	6°C/second max.			

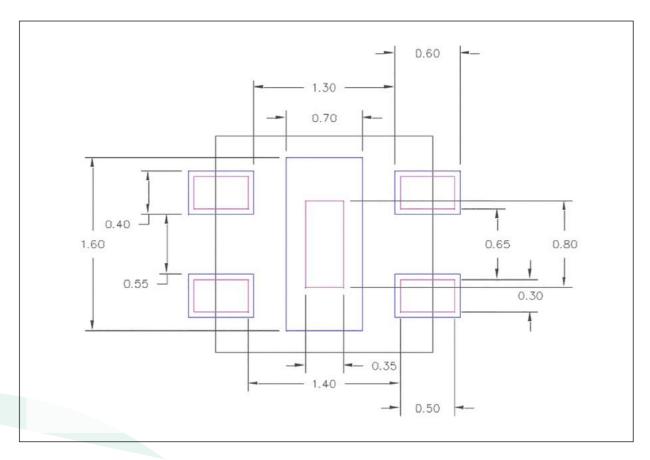




It is recommended to use a no-clean solder paste for soldering the sensor component on a PCB. There should not be any board wash process, to prevent the sensor area to get in contact with cleaning agents or other liquid materials.

The recommended ENS210 landing pattern can be found in the drawing below in blue. A  $100\mu m$  thick stencil can be used and the stencil apertures are indicated in violet.

Figure 38: Footprint Design







#### Storage and Handling

The ENS210 moisture sensitivity level is 1 (MSL1), which corresponds to an unlimited out-of-bag lifetime at  $T = 30^{\circ}C$ ; RH = 85%RH maximum.

Precautions should be taken to prevent electrostatic discharge (ESD) from damaging the sensor product.

All input and output pins are protected against electrostatic discharge (ESD) under normal handling. When handling ensure that the appropriate precautions are taken as described in JESD625-A or equivalent standards.

The pick-up nozzle of the pick and place machine must be positioned in such a way on the component that it fully covers the cavity of the package, to avoid the leakage of air. Because the ENS210 uses a cavity package, where the sensor is in direct contact with the environment, physical contact with sensor should be prevented at all times. If required, dust particles can be removed by gently blowing air inside the cavity of the package. Do not brush or wipe.

For proper operation of the product, exposure to Volatile Organic Compounds (VOCs) should be avoided. During manufacturing, transport and storage, VOCs may originate from out-gassing of glues, adhesive tapes and packaging materials such as bags and foams.

In operation, VOCs might naturally be present in the environment as vapors of, for example, ethanol, acetone and isopropyl alcohol. It is important to realize that some of these contaminants can cause offsets in the sensor reading that may not recover naturally. The same holds for atmospheric pollutants such as ammonia, nitric oxide and chlorine.

Offsets in the sensor reading due to exposure to contaminants may be reversed in certain cases by applying the recommended Reconditioning Procedure (see below Reconditioning). Direct contact with liquid cleaning agents, or rubbing the surface with brushes or cotton-tip sticks, should be avoided at all times.

The sensor is not damaged by water immersion or condensation. The sensor will recover completely when the water evaporates.

Sensor readings are not impacted by high intensity light. This was validated by exposing the sensor to the complete spectrum of a Xe-arc lamp at light levels of 400W/m2 in the range of 290-800 nm, in accordance with ASTM4459.





#### Reconditioning

The procedures indicated below accelerate the reconditioning of the sensor back to its calibrated state.

#### After Soldering

After soldering according to Figure 36, RHS reading may show an offset of -2%RH compared to its calibrated value. This offset will slowly disappear if the device is exposed to normal ambient conditions (e.g.  $T = 25^{\circ}C$ , RH = 45%RH, for a week). To accelerate return to its initial calibrated state, we recommend to expose devices to  $25^{\circ}C$  and 75%RH for 12 hours. This would reduce the time it has to recover at normal ambient conditions before usage.

#### After Extreme Conditions

If the device is exposed to conditions outside the 'specified safe operating range' for a long time, RH reading may show an offset compared to its calibrated value.

The following procedure accelerates the reconditioning of the sensor back to its calibrated state:

- A mild baking step at 105°C for 12 hours, to evaporate the contaminant.
- A hydration step at 25°C and 75%RH for 12 hours, to rehydrate the sensor material.
- A soak step at normal ambient conditions (e.g. 23 °C ± 3 °C, 35-55%RH) for 24 hours.

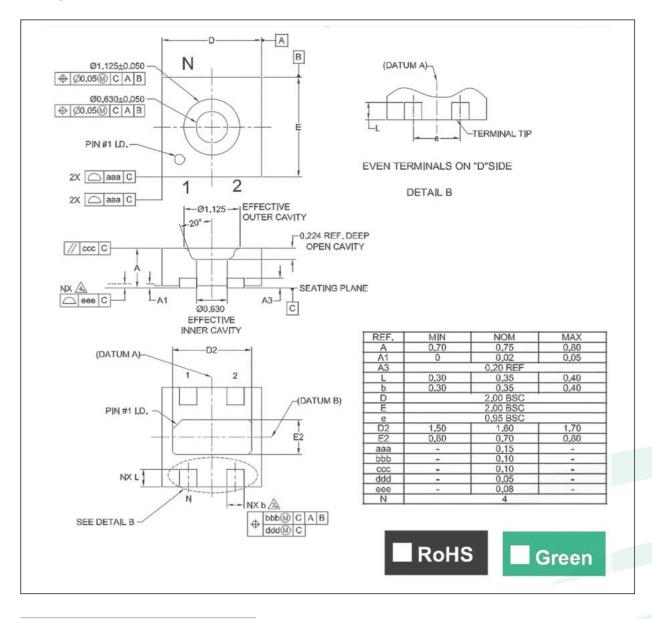




#### Package Drawings & Markings

The ENS210 has QFN4 package: plastic thermal enhanced very thin small outline package; no leads; 4 terminals; body  $2.0 \times 2.0 \times 0.75$ mm, see Figure 39.

Figure 39: Package Outline



#### Note(s):

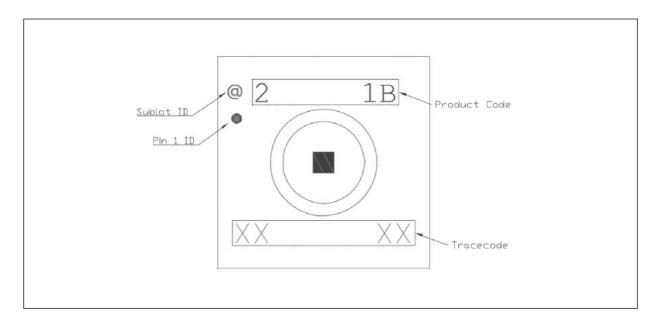
- 1. Dimensioning and tolerancing conform to ASME Y14.5M-1994.
- 2. All dimensions are in millimeters. Angles are in degrees.
- 3. Dimension b applies to metallized terminal and is measured between 0.15mm and 0.30mm from terminal tip.
- 4. Unilateral coplanarity applies to the exposed heat sink slug as well as the terminal.
- 5.N is the total number of terminals.





# Marking Information

Figure 40: Marking of ENS210







## **Ordering & Contact Information**

Figure 41: Ordering Information

Ordering Code	Package	Marking	Description	Delivery Form	Delivery Quantity
ENS210-LQFM	QFN4	21B	Plastic thermal enhanced very thin small outline package; no leads; 4 terminals; body $2.0 \times 2.0 \times 0.75$ mm	•	3500 pcs/reel

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## **Document Status**

Document Status	Product Status	Definition
Product Preview	Pre-Development	Information in this datasheet is based on product ideas in the planning phase of development. All specifications are design goals without any warranty and are subject to change without notice
Preliminary Datasheet	Pre-Production	Information in this datasheet is based on products in the design, validation or qualification phase of development.  The performance and parameters shown in this document are preliminary without any warranty and are subject to change without notice
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# **Revision Information**

Changes from 1-00 (2016-Oct-24) to current revision 1-02 (2018-Feb-19)	Page	
1-00 (2016-Oct-24) to 1-01 (2018-Jan-26)		
Updated Applications	4	
Updated Figure 8 and notes under it	9	
Updated Figure 14	13	
1-01 (2018-Jan-26) to 1-02 (2018-Feb-19)		
Updated Figure 1	3	
Updated Figure 6	7	
Updated Figure 8	9	
Updated Figure 9	10	
Added RH Accuracy at Various Temperatures section	14	
Updated text under The I <sup>2</sup> C Interface	15	
Updated code under Processing T_VAL and H_VAL	22	
Updated Figure 40	38	

Changes from 1-02 (2018-Feb-19) to current revision 2.00 (2019-Dec-03)	Page
Updated notes onder figure 7	8



# **Revision Information**

Changes from ams version 2-00 (2019-Dec-03) to Current Version SC-000897-DS-1 (2020-Aug-07)	Page	
ScioSense branding and release for ALL pages		
Updated Figure 1	3	
Updated text of the paragraph	24	
Updated Figure 22	25	
Updated and added text content of Detailed Register Description	26	
Due to adding text and Figure 24, it impacts on the content of Page 24-28 and Figure numbers from 24 onwards		
Added description of Register DIE_REV	26	
Added Figure 24	26	
Updated the content of Storage and Handling	35	
Updated Figure 40	38	
Updated Figure 41	39	
Updated text of Copyrights & Disclaimer	41	
Updated text of Revision Information	43	
Updated text of Content Guide	45	

Changes from version SC-000897-DS-1 (2020-Aug-07) to current version SC-000897-2 (2020-Dec-04)	Page
ScioSense branding and visual	Cover page
Lay-out reformat ALL pages	
Content Guide from page 43 to page 2	2
Updated Figure 7	8
Updated Figure 8	9
Updated Figure 12	12
Updated Figure 14	13
Updated Figure 15	14

#### Note(s):

<sup>1.</sup> Page and figure numbers from the previous version may differ from page and figure numbers in the current revision.

<sup>2.</sup> Correction of typographical errors is not explicitly mentioned.



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